NSN 5962-01-094-9069

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View Online at https://aerobasegroup.com/nsn/5962-01-094-9069
Body Length:
Between 0.780 inches and 0.820 inches
Body Width:
Between 0.275 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
1.25 watts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
55.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and dynamic and w/strobe and w/enable
nclosure Material:
Ceramic
nclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
nput Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
0.5 volts power source and 25.0 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Rom
Memory Capacity:
Jnknown
Test Data Document:
21101-49a0295 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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